## **CURRENT CLAIMS**

A copy of the claims is provided below for the convenience of the Examiner. The claims are not amended.

Claims 1-22 (Cancelled).

23. (Previously Presented) A band-gap reference circuit having a plurality of possible operating states which respectively correspond to a plurality of possible values of a band-gap reference voltage, comprising:

a current source;

a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said current develops a combined voltage across said series connection of said resistor and said base-emitter diode;

a further base-emitter diode;

an adjustment circuit having an output coupled to said current source and having inputs respectively coupled to said circuit branch and said further base-emitter diode for adjusting a band-gap reference voltage based on a said combined voltage and a base-emitter voltage of said further base-emitter diode; and

a start circuit having an output connected to one of said inputs of said adjustment circuit for preventing operation in one of said operating states.

- 24. (Previously Presented) The band-gap reference circuit of Claim 23, wherein said start circuit is for injecting a current into the emitter of said further base-emitter diode.
- 25. (Previously Presented) The band-gap reference circuit of Claim 24, wherein said start circuit has an output connected to said output of said adjustment circuit for applying a bias voltage to said output of said adjustment circuit.
- 26. (Previously Presented) The band-gap reference circuit of Claim 23, wherein said start circuit has an output connected to said output of said adjustment circuit for applying a bias voltage to said output of said adjustment circuit.
- 27. (Previously Presented) The band-gap reference circuit of Claim 23, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

28. (Previously Presented) A band-gap reference circuit, comprising:

a current source for generating a current, said current source normally requiring a response time to transition from a first operating state thereof wherein said current source actively generates no current to a second operating state thereof wherein said current source actively generates said current;

a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said received current develops a combined voltage across said series connection of said resistor and said base-emitter diode;

a further base-emitter diode;

an adjustment circuit having an output coupled to said current source and having inputs respectively coupled to said circuit branch and said further base-emitter diode for adjusting a band-gap reference voltage based on a said combined voltage and a base-emitter voltage of said further base-emitter diode; and

a start circuit having an output coupled to said output of said adjustment circuit for reducing said response time.

29. (Previously Presented) The band-gap reference circuit of Claim 28, wherein said start circuit is for applying a bias voltage to said output of said adjustment circuit.

- 30. (Previously Presented) The band-gap reference circuit of Claim 29, wherein said start circuit has an output connected to said further base-emitter diode for injecting a current into the emitter of said further base-emitter diode.
- 31. (Previously Presented) The band-gap reference circuit of Claim 28, wherein said start circuit has an output connected to said further base-emitter diode for injecting a current into the emitter of said further base-emitter diode.
- 32. (Previously Presented) The band-gap reference circuit of Claim 28, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.
- 33. (Previously Presented) The band-gap reference circuit of Claim 28, wherein said band-gap reference circuit has a plurality of possible operating states which respectively correspond to a plurality of possible values of said band-gap reference voltage, and wherein said start circuit is coupled to said adjustment circuit and cooperable therewith for preventing operation in one of said operating states.
- 34. (Previously Presented) The band-gap reference circuit of Claim 33, wherein said start circuit is for injecting a current into the emitter of said further base-emitter diode.

- 35. (Previously Presented) The band-gap reference circuit of Claim 34, wherein said start circuit is for applying a bias voltage to said output of said adjustment circuit.
- 36. (Previously Presented) The band-gap reference circuit of Claim 33, wherein said start circuit is for applying a bias voltage to said output of said adjustment circuit.
- 37. (Previously Presented) The band-gap reference circuit of Claim 33, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

A cellular telephone, comprising:

a voltage regulator capable of generating a regulated output voltage;

analog-to-digital circuitry capable of converting analog signals into digital signals; and

a band-gap reference circuit coupled to said voltage regulator and said analog-to-digital

circuitry and capable of supplying a band-gap reference voltage to said voltage regulator and said

analog-to-digital circuitry, wherein said band-gap reference voltage is relatively constant across

an operating temperature range, said band-gap reference circuit having a plurality of possible

operating states which respectively correspond to a plurality of possible values of said band-gap

reference voltage, said band-gap reference circuit including a current source, a circuit branch

coupled to said current source for receiving current generated by said current source, said circuit

branch including a resistor having a positive temperature coefficient connected in series with a

base-emitter diode having a negative temperature coefficient, wherein said current develops in

said circuit branch a combined voltage across said series connection of said resistor and said

base-emitter diode, a further base-emitter diode, an adjustment circuit having an output coupled

to said current source and having inputs respectively coupled to said circuit branch and said

further base-emitter diode for adjusting a band-gap reference voltage based on a said combined

voltage and a base-emitter voltage of said further base-emitter diode, and a start circuit having an

output connected to one of said inputs of said adjustment circuit for preventing operation in one

of said operating states.

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39. (Previously Presented) The cellular telephone of Claim 38, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

A cellular telephone, comprising:

a voltage regulator capable of generating a regulated output voltage;

analog-to-digital circuitry capable of converting analog signals into digital signals; and

a band-gap reference circuit coupled to said voltage regulator and said analog-to-digital

circuitry and capable of supplying a band-reference voltage to said voltage regulator and said

analog-to-digital circuitry wherein said band-gap reference voltage is relatively constant across

an operating temperature range, said band-gap reference circuit including a current source for

generating a current, said current source normally requiring a response time to transition from a

first operating state thereof wherein said current source actively generates no current to a second

operating state thereof wherein said current source actively generates said current, a circuit

branch coupled to said current source for receiving current generated by said current source, said

circuit branch including a resistor having a positive temperature coefficient connected in series

with a base-emitter diode having a negative temperature coefficient, wherein said received

current develops in said circuit branch a combined voltage across said series connection of said

resistor and said base-emitter diode, a further base-emitter diode, an adjustment circuit having an

output coupled to said current source and having inputs respectively coupled to said circuit

branch and said further base-emitter diode for adjusting a band-gap reference voltage based on a

said combined voltage and a base-emitter voltage of said further base-emitter diode, and a start

circuit having an output coupled to said output of said adjustment circuit for reducing said

response time.

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- 41. (Previously Presented) The band-gap reference circuit of Claim 40, wherein said band-gap reference circuit has a plurality of possible operating states which respectively correspond to a plurality of possible values of said band-gap reference voltage, and wherein said start circuit is coupled to said adjustment circuit and cooperable therewith for preventing operation in one of said operating states.
- 42. (Previously Presented) The band-gap reference circuit of Claim 41, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.
- 43. (Previously Presented) The cellular telephone of Claim 40, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

A band-gap reference circuit comprising:

a current source;

a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said current develops a combined voltage across said series connection of said resistor and said base-emitter diode;

a further base-emitter diode;

an adjustment circuit for adjusting a band-gap reference voltage based on said combined voltage and a base-emitter voltage of said further base-emitter diode; and

a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

A cellular telephone, comprising:

a voltage regulator capable of generating a regulated output voltage;

analog-to-digital circuitry capable of converting analog signals into digital signals; and

a band-gap reference circuit coupled to said voltage regulator and said analog-to-digital circuitry and capable of supplying a band-gap reference voltage to said voltage regulator and said

an operating temperature range, said band-gap reference circuit including a current source, a

analog-to-digital circuitry, wherein said band-gap reference voltage is relatively constant across

circuit branch coupled to said current source for receiving current generated by said current

source, said circuit branch including a resistor having a positive temperature coefficient

connected in series with a base-emitter diode having a negative temperature coefficient, wherein

said current develops in said circuit branch a combined voltage across said series connection of

said resistor and said base-emitter diode, a further base-emitter diode, an adjustment circuit for

adjusting a band-gap reference voltage based on said combined voltage and a base-emitter

voltage of said further base-emitter diode, and a correction circuit coupled to said adjustment

circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap

reference voltage caused by said further base-emitter diode.